PC100 UNBUFFERED DIMM

1GB 64x8

DESCRIPTION:

This document describes Aplus 128M x 64-bit 1GB PC100 CL2 SDRAM (Synchronous DRAM) low profile memory module The components on this module include sixteen stacked 128M x 8-bit (thirty-two 64M x 8-bit) PC100 SDRAM This 168-pin DIMM uses gold contact fingers and requires +3.3V. The electrical and mechanical specifications are as follows:

FEATURES:

Single 3.3V ± 0.3V power supply
Burst mode operation
Auto & self refresh capability
LVTTL compatible inputs and outputs
MRS cycle with address key programs
Latency (Access from column address)
Burst length (1,2,4,8 & Full page)
Data scramble (sequential & interleave)
All inputs are sampled at the positive going
edge of the system clock
Timing Reference: CL-tRCD-tRP (2-2-2)
Serial presence detect with EEPROM

PERFORMANCE:

CLK cycle time (tCC)
CLK to output (tSAC)
Row active time (tRAS)
Row cycle time (tRC)
Power Dissipation
Operating Temperature
Storage Temperature

10ns (min.) /1000ns (max.)
50ns (min.) /100ns (max.)
70ns (min.)
70ns (min.)
70ns (min.)
70ns (min.)
70ns (min.)
70ns (min.)
70ns (min.)